Bulletin I27245 09/06

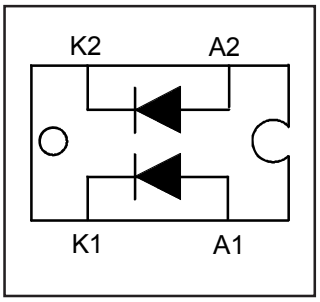
International
IOR Rectifier

HFA120FA60P

HEXFRED™

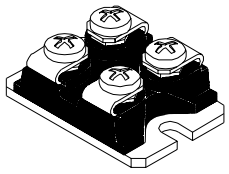
Ultrafast, Soft Recovery Diode

V_R = 600V
V_F(typ.)* = 1.4V
$I_{F(AV)}$ = 60A
Q_{rr} (typ.) = 270nC
I_{RRM}(typ.) = 7.0A
t_{rr}(typ.) = 65ns
$di_{(rec)M}/dt$ (typ.)* = 270A/µs



Features

- Fast Recovery time characteristic
- Eletrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- UL Pending
- Totally Lead-Free



SOT-227

Description

This SOT-227 modules with FRED rectifier are available in two basic configurations. They are the antiparallel and the parallel configurations. The antiparallel configuration (HFA120EA60) is used for simple series rectifier and high voltage application. The parallel configuration (HFA120FA60) is used for simple parallel rectifier and high current application.
The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built. These modules are intended for general applications such as power supplies, battery chargers, electronic welders, motor control, DC chopper, and inverters.

Absolute Maximum Ratings (per Leg)

	Parameter	Max.	Units
V_R	Cathode-to-Anode Voltage	600	V
I_F @ T_C = 25°C	Continuous Forward Current	75	A
I_F @ T_C = 100°C	Continuous Forward Current	40	
I_{FSM}	Single Pulse Forward Current	TBD	
I_{FRM}	Maximum Repetitive Forward Current	180	
V_{ISOL}	RMS Isolation Voltage, Any Terminal to Case, t=1 min	2500	V
P_D @ T_C = 25°C	Maximum Power Dissipation	180	W
P_D @ T_C = 100°C	Maximum Power Dissipation	71	
T_J T_{STG}	Operating Junction and Storage Temperature Range		°C

*125 °C

Electrical Characteristics (per Leg) @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
V_{BR}	Cathode Anode Breakdown Voltage	600	——	——	V	I_R = 100µA
V_{FM}	Max Forward Voltage	——	1.5	1.7	V	I_F = 60A
		——	1.9	2.1		I_F = 120A — See Fig. 1
		——	1.4	1.6		I_F = 60A, T_J = 125°C
I_{RM}	Max Reverse Leakage Current	——	2.5	20	µA	V_R = V_R Rated — See Fig. 2
		——	130	2000		T_J = 125°C, V_R = 0.8 x V_R Rated
C_T	Junction Capacitance	——	120	170	pF	V_R = 200V — See Fig. 3

Dynamic Recovery Characteristics (per Leg) @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions	
t_{rr}	Reverse Recovery Time	——	34	——	ns	I_F = 1.0A, di_f/dt = 200A/µs, V_R = 30V	
t_{rr1}	See Fig. 5, 6 & 16	——	65	98		T_J = 25°C	I_F = 60A
t_{rr2}		——	130	200		T_J = 125°C	
I_{RRM1}	Peak Recovery Current	——	7.0	13	A	T_J = 25°C	V_R = 200V
I_{RRM2}	See Fig. 7& 8	——	13	23		T_J = 125°C	
Q_{rr1}	Reverse Recovery Charge	——	270	410	nC	T_J = 25°C	di_f/dt = 200A/µs
Q_{rr2}	See Fig. 9 & 10	——	490	740		T_J = 125°C	
$di_{(rec)M}/dt1$	Peak Rate of Fall of Recovery Current	——	350	——	A/µs	T_J = 25°C	
$di_{(rec)M}/dt2$	During t_b See Fig. 11 & 12	——	270	——		T_J = 125°C	

Thermal - Mechanical Characteristics

	Parameter	Min.	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case, Single Leg Conducting	——	——	0.70	°C/W K/W
	Junction-to-Case, Both Legs Conducting	——	——	0.35	
$R_{\theta CS}$	Case-to-Sink, Flat , Greased Surface	——	0.05	——	
Wt	Weight	——	30	——	gm
	Mounting Torque	——	1.3	——	(N•m)

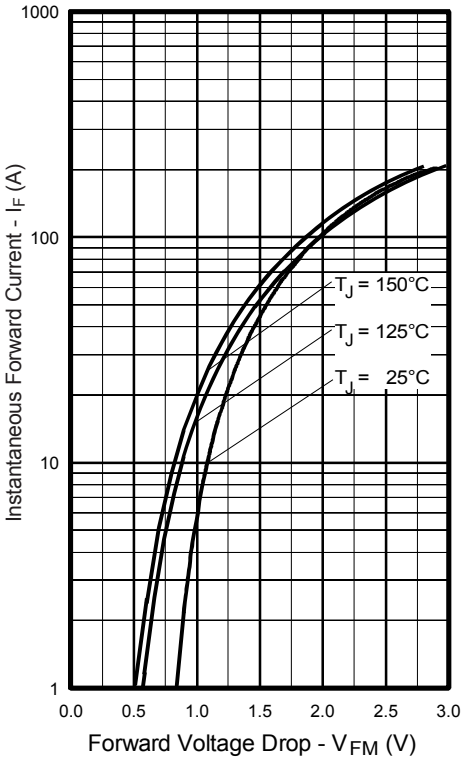


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current, (per Leg)

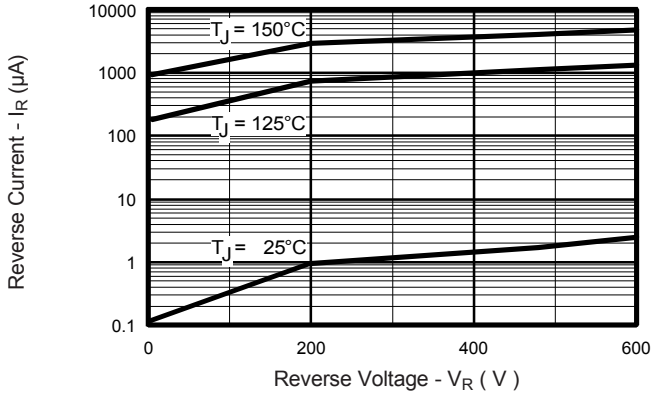


Fig. 2 - Typical Reverse Current vs. Reverse Voltage, (per Leg)

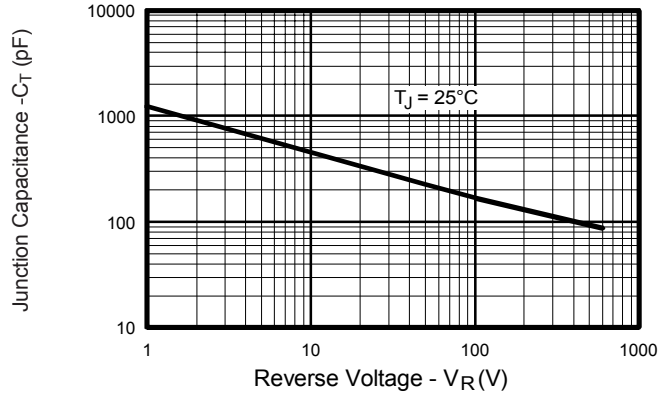


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, (per Leg)

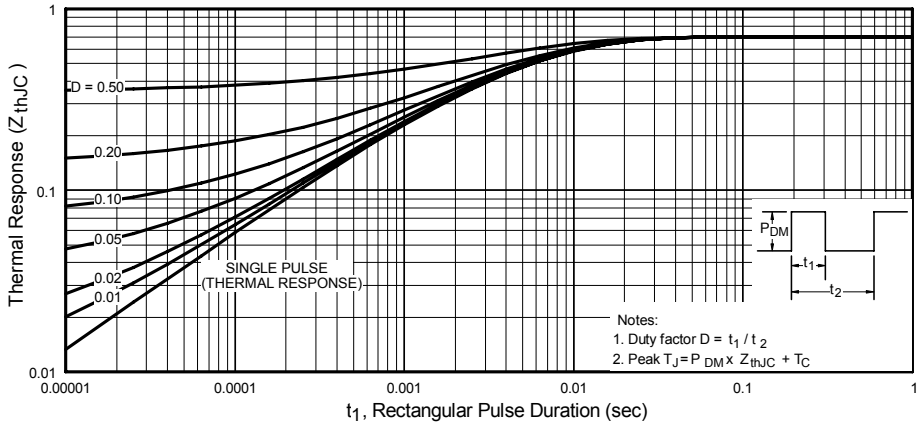


Fig. 4 - Maximum Thermal Impedance Z_{thjc} Characteristics, (per Leg)

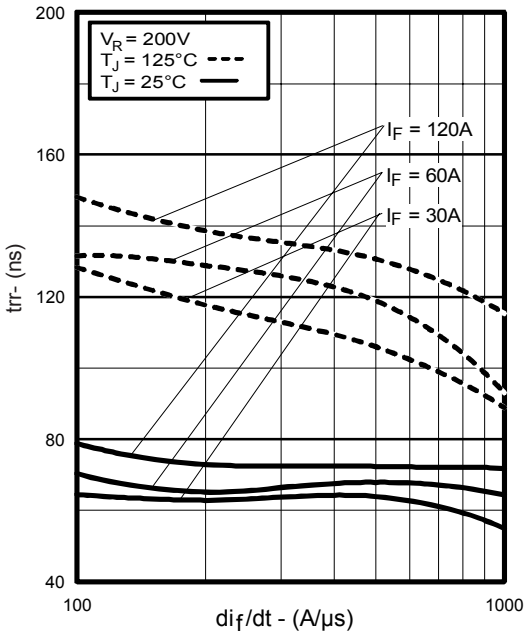


Fig. 5 - Typical Reverse Recovery vs. di_f/dt, (per Leg)

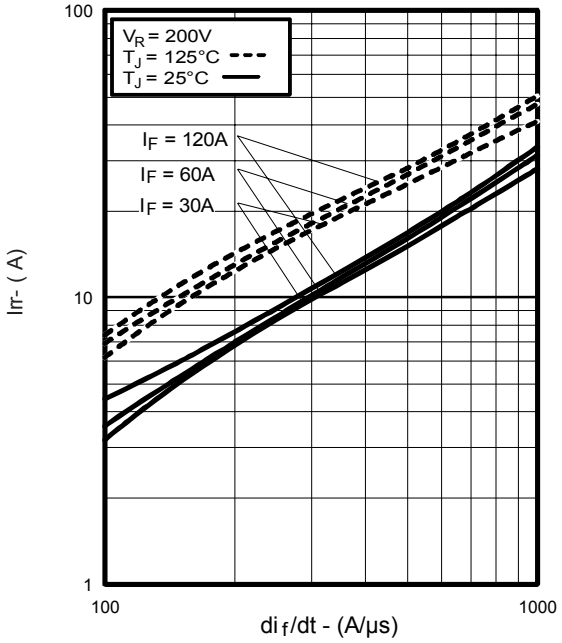


Fig. 6 - Typical Recovery Current vs. di_f/dt, (per Leg)

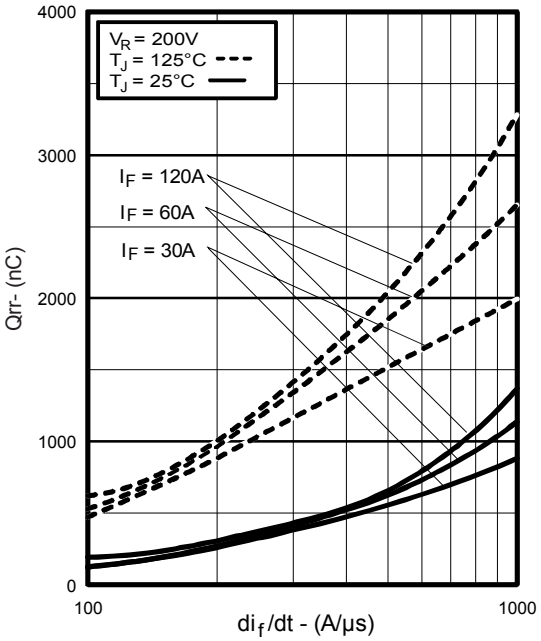


Fig. 7 - Typical Stored Charge vs. di_f/dt, (per Leg)

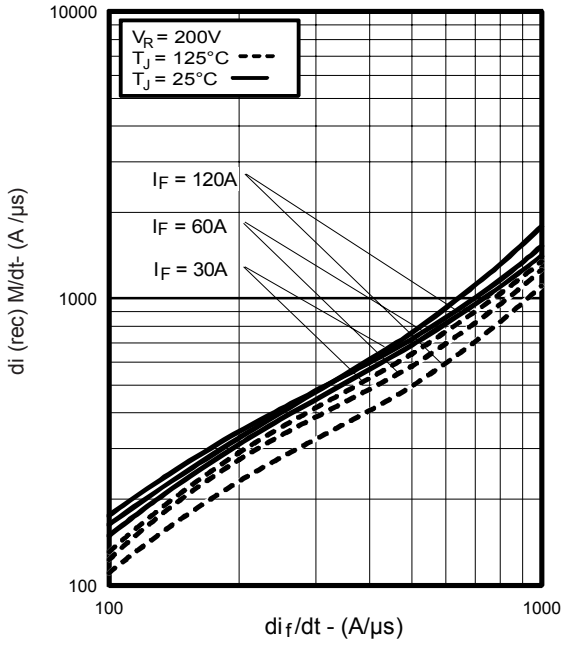


Fig. 8 - Typical $di_{(rec)M}/dt$ vs. di_f/dt, (per Leg)

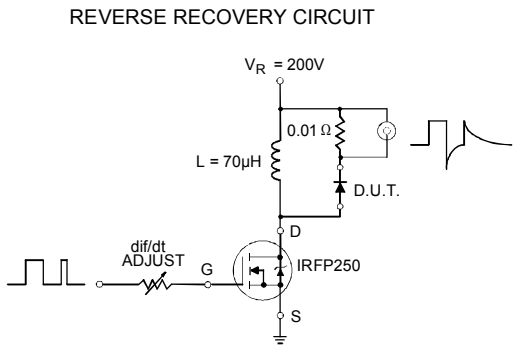


Fig. 9 - Reverse Recovery Parameter Test Circuit

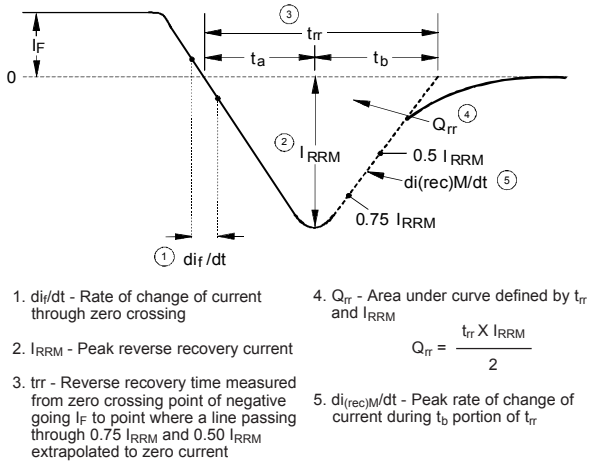


Fig. 10 - Reverse Recovery Waveform and Definitions

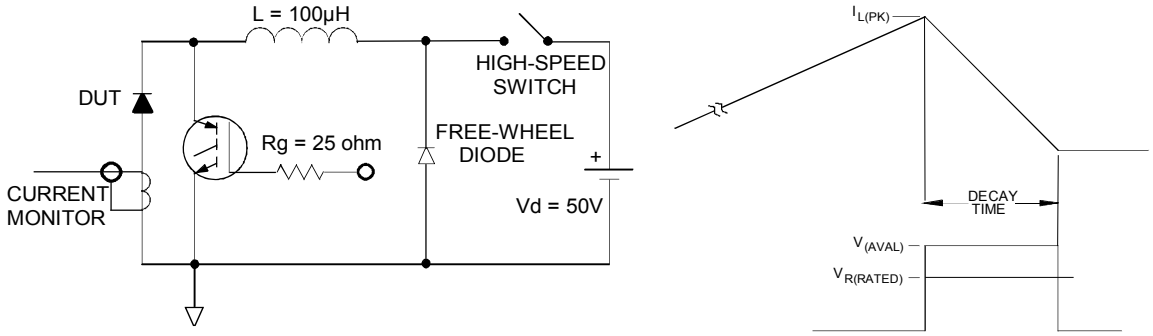
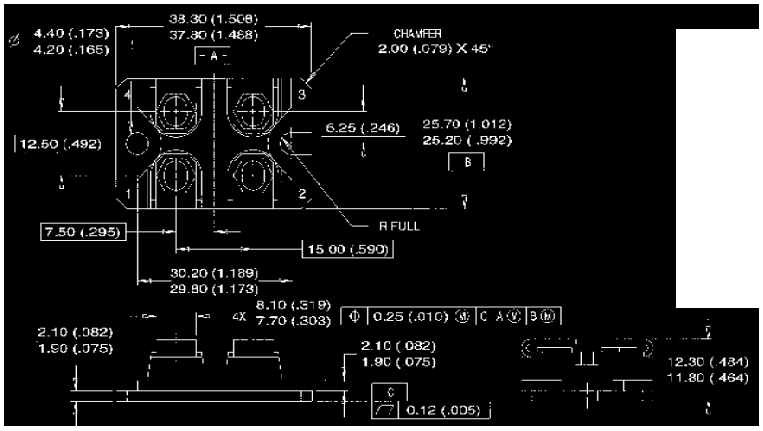


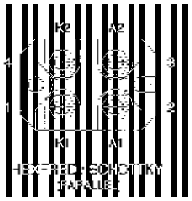
Fig. 11 - Avalanche Test Circuit and Waveforms

SOT-227 Package Details



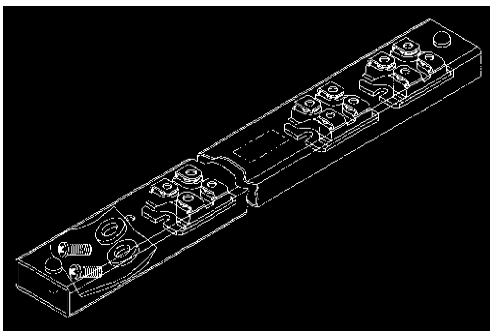
NOTES:
1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).

LEAD ASSIGNMENTS



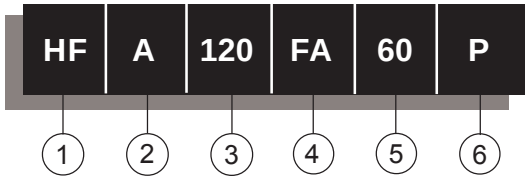
Tube

QUANTITIES PER TUBE IS 10
M4 SREW AND WASHER INCLUDED



Ordering Information Table

Device Code



1	-	Hexfred Family
2	-	Process: A electron irradiated
3	-	Current Rating (120 = 120A)
4	-	Package Indicator (SOT-227)
5	-	Voltage Rating (60 = 600V)
6	-	• none = Standard Production • P = Lead-Free

Data and specifications subject to change without notice.
This product has been designed for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

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08/06

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